

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**
(Not for submission under 37 CFR 1.99)

Application Number		10583523
Filing Date		2007-07-24
First Named Inventor		Choudhury et al.
Art Unit		2874
Examiner Name		J. M. Bedtelyon
Attorney Docket Number		A5-013 US

U.S.PATENTS

Examiner Initial*	Cite No	Patent Number	Kind Code ¹	Issue Date	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines where Relevant Passages or Relevant Figures Appear
	1	7197224		2007-03-27	Rolson et al.	

If you wish to add additional U.S. Patent citation information please click the Add button.

U.S.PATENT APPLICATION PUBLICATIONS

Examiner Initial*	Cite No	Publication Number	Kind Code ¹	Publication Date	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines where Relevant Passages or Relevant Figures Appear
	1					

If you wish to add additional U.S. Published Application citation information please click the Add button.

FOREIGN PATENT DOCUMENTS

Examiner Initial*	Cite No	Foreign Document Number ³	Country Code ² i	Kind Code ⁴	Publication Date	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines where Relevant Passages or Relevant Figures Appear	T ⁵
	1	03-221853	JP		1993-03-12	Nippon Telegraph & Telephone Corp.		<input checked="" type="checkbox"/>
	2	03-299624	JP		1993-05-07	Nippon Telegraph & Telephone Corp.		<input checked="" type="checkbox"/>
	3	05-094252	JP		1994-11-04	Sony Corp.		<input checked="" type="checkbox"/>

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**
(Not for submission under 37 CFR 1.99)

Application Number	10583523
Filing Date	2007-07-24
First Named Inventor	Choudhury et al.
Art Unit	2874
Examiner Name	J. M. Bedtelyon
Attorney Docket Number	A5-013 US

4	06-314786	JP		1996-07-02	Nippon Telegraph & Telephone Corp.		<input checked="" type="checkbox"/>
5	2000-301490	JP		2002-04-10	Fujitsu Quantum Devices Ltd.		<input checked="" type="checkbox"/>
6	2001-272597	JP		2003-03-19	NGK Insulators Ltd.		<input checked="" type="checkbox"/>
7	2002-005415	JP		2003-07-25	NEC Corp.		<input checked="" type="checkbox"/>

If you wish to add additional Foreign Patent Document citation information please click the Add button

NON-PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, pages(s), volume-issue number(s), publisher, city and/or country where published.	T ⁵
	1	L PAVESI, "Will Silicon Be The Photonic Material Of The Third Millenium?", Journal of Physics: Condensed Matter, 24 April 2003, Pages R1169-96, Vol. 15, IOP Publishing Ltd., United Kingdom.	<input type="checkbox"/>

If you wish to add additional non-patent literature document citation information please click the Add button

EXAMINER SIGNATURE

Examiner Signature	Date Considered
--------------------	-----------------

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through a citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ See Kind Codes of USPTO Patent Documents at www.USPTO.GOV or MPEP 901.04. ² Enter office that issued the document, by the two-letter code (WIPO Standard ST.3). ³ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁴ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁵ Applicant is to place a check mark here if English language translation is attached.